

N-CHANNEL ENHANCEMENT MODE FIELD MOSFET
Product Summary

$V_{(BR)DSS}$	$R_{DS(ON)}$	Package	I_D $T_A = +25^\circ C$
600V	160Ω @ $V_{GS} = 10V$	SC59 SOT23	70mA

Description

This new generation uses advanced planar technology MOSFET, provide excellent high Voltage and fast switching, making it ideal for small-signal and level shift applications.

Applications

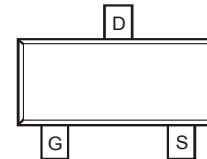
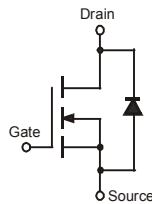
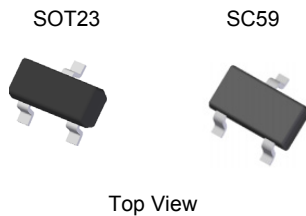
- Motor Control
- Backlighting
- DC-DC Converters
- Power Management Functions

Features

- Low Input Capacitance
- High BVD_{SS} rating for power application
- Low Input/Output Leakage
- **Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

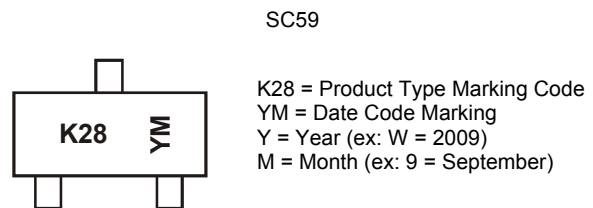
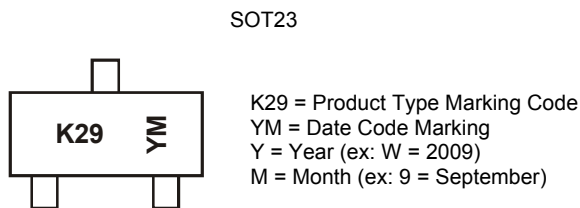
Mechanical Data

- Case: SC59 / SOT23
- Case Material: Molded Plastic "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin annealed over Copper leadframe Solderable per MIL-STD-202, Method 208 ^{Ⓔ3}
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)


Ordering Information (Note 4)

Part Number	Case	Packaging
BSS127SSN-7	SC59	3000/Tape & Reel
BSS127S-7	SOT23	3000/Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See <http://www.diodes.com> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com>.

Marking Information

Date Code Key

Year	2009	2010	2011	2012	2013	2014	2015
Code	W	X	Y	Z	A	B	C

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	600	V
Gate-Source Voltage			V_{GSS}	± 20	V
Continuous Drain Current (Note 5) $V_{GS} = 10\text{V}$	Steady State	$T_A = +25^\circ\text{C}$	I_D	50	mA
		$T_A = +70^\circ\text{C}$		40	
Continuous Drain Current (Note 6) $V_{GS} = 10\text{V}$	Steady State	$T_A = +25^\circ\text{C}$	I_D	70	mA
		$T_A = +70^\circ\text{C}$		55	
Continuous Drain Current (Note 5) $V_{GS} = 5\text{V}$	Steady State	$T_A = +25^\circ\text{C}$	I_D	45	mA
		$T_A = +70^\circ\text{C}$		35	
Continuous Drain Current (Note 6) $V_{GS} = 5\text{V}$	Steady State	$T_A = +25^\circ\text{C}$	I_D	65	mA
		$T_A = +70^\circ\text{C}$		50	
Pulsed Drain Current @ $T_{SP} = +25^\circ\text{C}$ (Notes 7)			I_{DM}	0.16	A

Thermal Characteristics

Characteristic	Symbol	Value	Units
Power Dissipation, @ $T_A = +25^\circ\text{C}$ (Note 5)	P_D	0.61	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^\circ\text{C}$ (Note 5)	$R_{\theta JA}$	204	$^\circ\text{C/W}$
Power Dissipation, @ $T_A = +25^\circ\text{C}$ (Note 6)	P_D	1.25	W
Thermal Resistance, Junction to Ambient @ $T_A = +25^\circ\text{C}$ (Note 6)	$R_{\theta JA}$	100	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV_{DSS}	600	—	—	V	$V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$
Zero Gate Voltage Drain Current $T_J = +25^\circ\text{C}$	I_{DSS}	—	—	0.1	μA	$V_{DS} = 600\text{V}, V_{GS} = 0\text{V}$
Gate-Body Leakage	I_{GSS}	—	—	± 100	nA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(th)}$	3	—	4.5	V	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(on)}$	—	80	160	Ω	$V_{GS} = 10\text{V}, I_D = 16\text{mA}$
		—	95	190		$V_{GS} = 5.0\text{V}, I_D = 16\text{mA}$
Forward Transfer Admittance	$ Y_{fs} $	—	76	—	mS	$V_{DS} = 10\text{V}, I_D = 16\text{mA}$
Diode Forward Voltage	V_{SD}	—	—	1.5	V	$V_{GS} = 0\text{V}, I_S = 16\text{mA}$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C_{iss}	—	21.8	—	pF	$V_{DS} = 25\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	—	2.2	—		
Reverse Transfer Capacitance	C_{rss}	—	0.3	—		
Total Gate Charge	Q_g	—	1.08	—	nC	$V_{GS} = 10\text{V}, V_{DD} = 300\text{V}, I_D = 0.01\text{A}$
Gate-Source Charge	Q_{gs}	—	0.08	—		
Gate-Drain Charge	Q_{gd}	—	0.50	—		
Turn-On Delay Time	$t_{D(on)}$	—	5.0	—	ns	$V_{DD} = 300\text{V}, V_{GS} = 10\text{V}, R_{GEN} = 6\Omega, I_D = 10\text{mA}$
Turn-On Rise Time	t_r	—	7.2	—	ns	
Turn-Off Delay Time	$t_{D(off)}$	—	28.7	—	ns	
Turn-Off Fall Time	t_f	—	168	—	ns	
Reverse Recovery Time	T_{rr}	—	131	—	ns	
Reverse Recovery Charge	Q_{rr}	—	32	—	nC	$V_R = 300\text{V}, I_F = 0.016\text{A}, di/dt = 100\text{A}/\mu\text{s}$

- Notes:
- Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
 - Device mounted on 1" x 1" FR-4 PCB with high coverage 2 oz. Copper, single sided.
 - Repetitive rating, pulse width limited by junction temperature, 10 μs pulse, duty cycle = 1%.
 - Short duration pulse test used to minimize self-heating effect.
 - Guaranteed by design. Not subject to production testing.

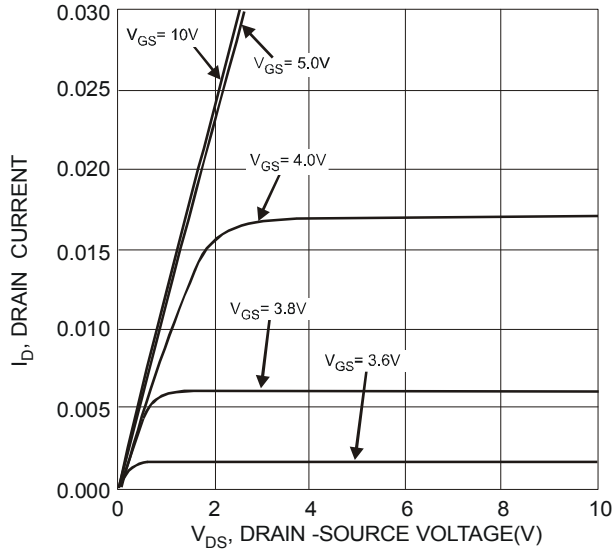


Figure 1 Typical Output Characteristics

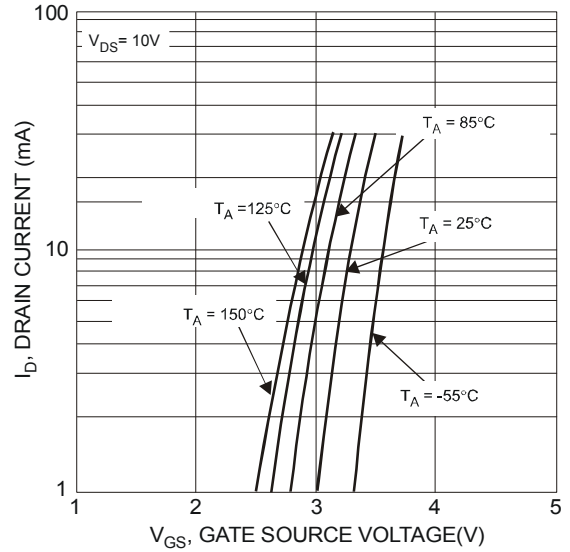


Figure 2 Typical Transfer Characteristics

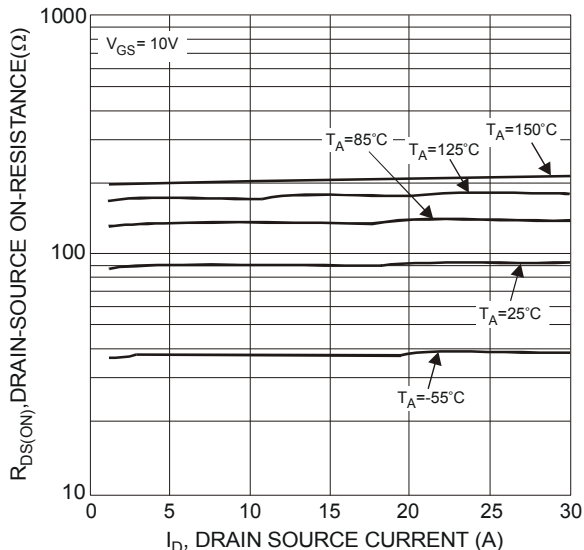


Figure 3 Typical On-Resistance vs. Drain Current and Temperature

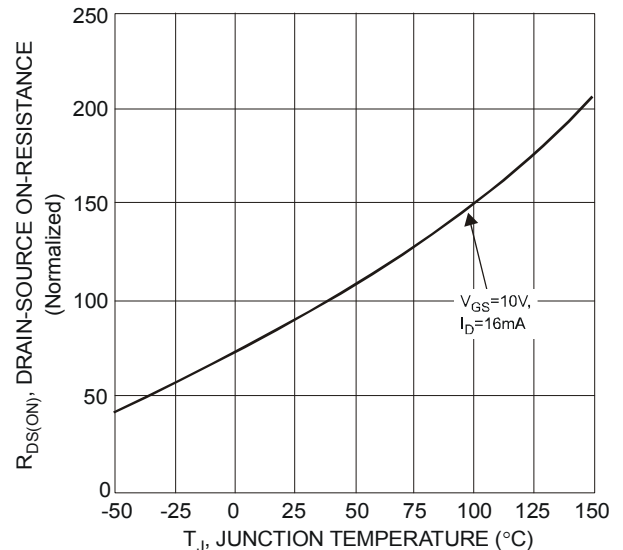


Figure 4 On-Resistance Variation with Temperature

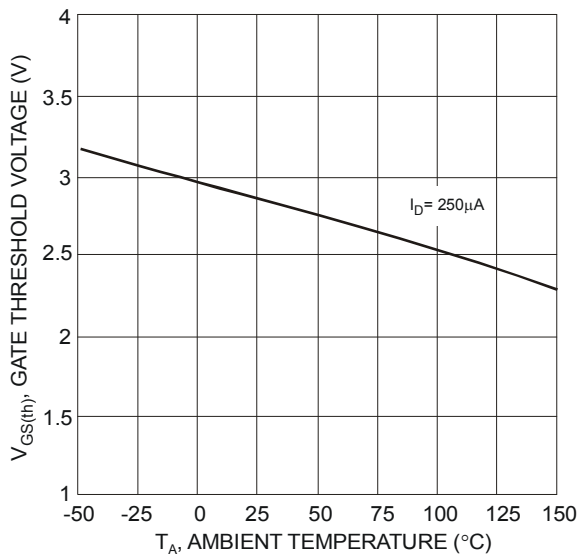


Figure 5 Gate Threshold Variation vs. Ambient Temperature

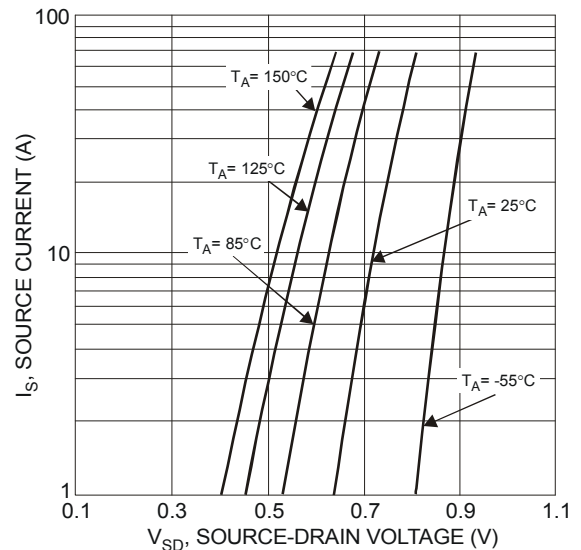


Figure 6 Diode Forward Voltage vs. Current

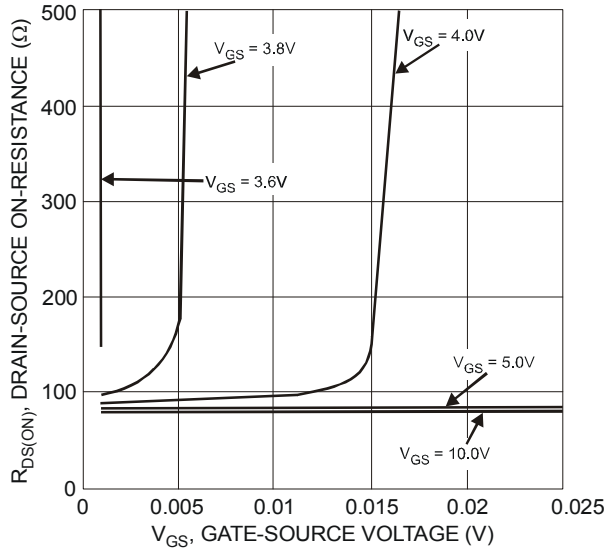


Figure 7 Typical On-Resistance vs. Drain Current and Gate Voltage

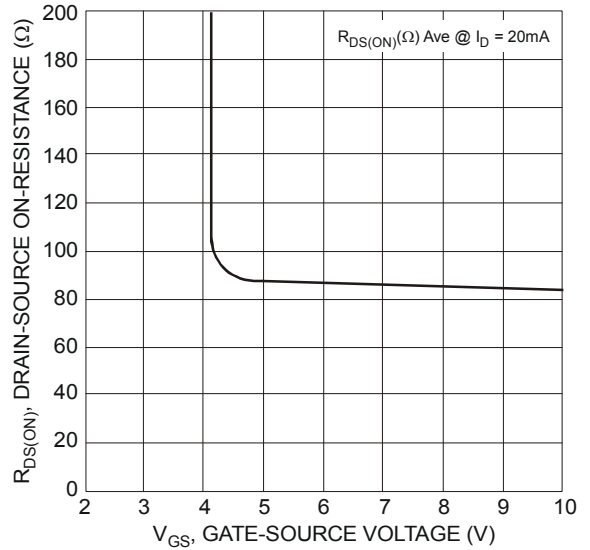


Figure 8 Typical Transfer Characteristic

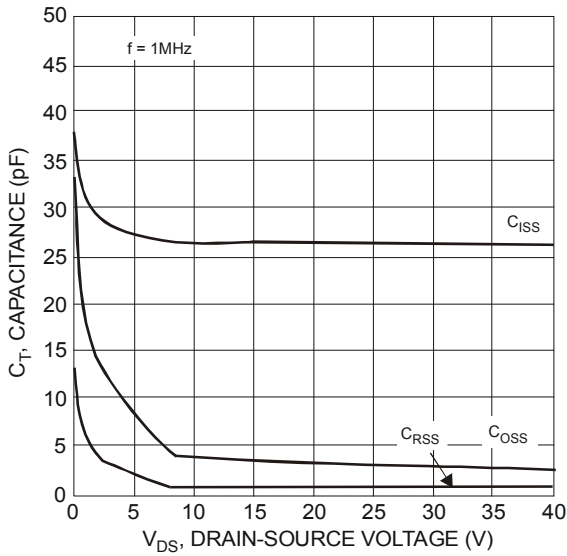


Figure 9 Typical Junction Capacitance

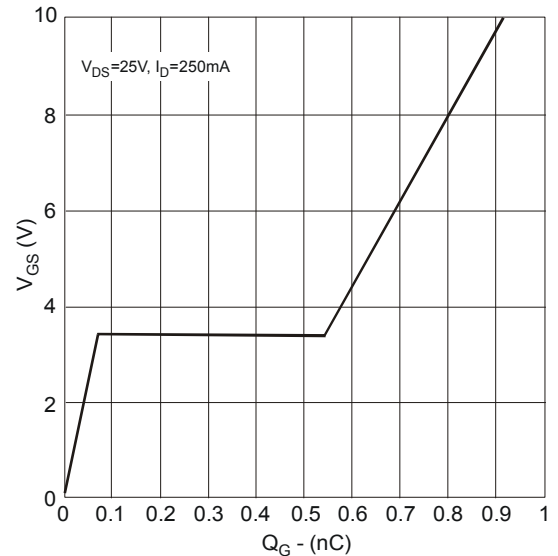


Figure 10 Gate Charge Characteristics

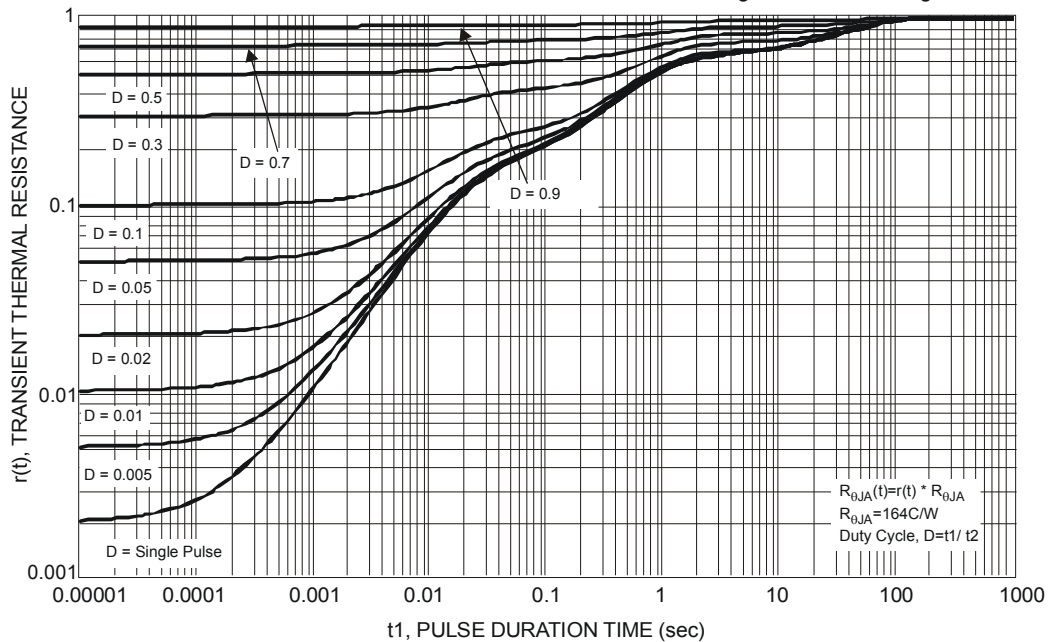
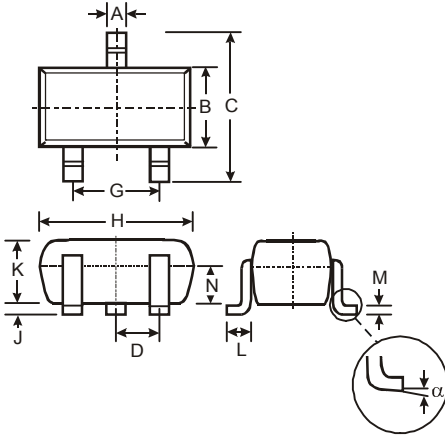


Figure 11 Transient Thermal Resistance

Package Outline Dimensions

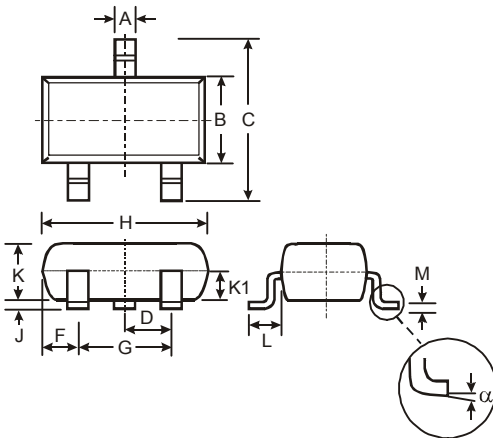
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

SC59



SC59			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
c	2.70	3.00	2.80
D	-	-	0.95
G	-	-	1.90
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
N	0.70	0.80	0.75
α	0°	8°	-
All Dimensions in mm			

SOT23

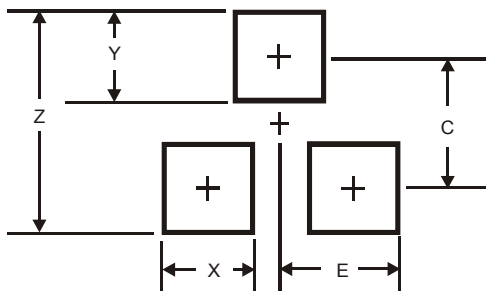


SOT23			
Dim	Min	Max	Typ
A	0.37	0.51	0.40
B	1.20	1.40	1.30
C	2.30	2.50	2.40
D	0.89	1.03	0.915
F	0.45	0.60	0.535
G	1.78	2.05	1.83
H	2.80	3.00	2.90
J	0.013	0.10	0.05
K	0.903	1.10	1.00
K1	-	-	0.400
L	0.45	0.61	0.55
M	0.085	0.18	0.11
α	0°	8°	-
All Dimensions in mm			

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

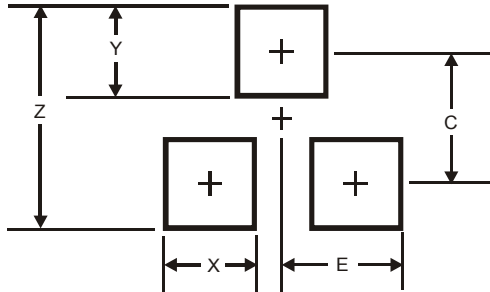
SC59



Dimensions	Value (in mm)
Z	3.4
X	0.8
Y	1.0
C	2.4
E	1.35

Suggested Pad Layout (cont.)

SOT23



Dimensions	Value (in mm)
Z	2.9
X	0.8
Y	0.9
C	2.0
E	1.35

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